Features
- DC to 1 GHz
- Flanged model
- Low VSWR

Applications
- High power RF transmission

CHF12545xBF Series 500 W Power RF Flanged Chip Termination

General Specifications
- Substrate: Beo
- Resistive Film: Thick Film
- Tab: Ag
- Cover Substrate: Al203
- Mounting Flange: Cu plated with Ni
- Resistance: 50 W
- Tolerance: ±5%
- Packaging: 50 pcs./tray

Absolute Ratings
- Power: 500 W
- Frequency: 1.0 GHz
- VSWR: 1.2 Maximum

Characteristic Curve

Product Dimensions

How To Order

REV. 12/15

*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011. Specifications are subject to change without notice. The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

This series is obsolete and not recommended for new designs.

OBSOLETE